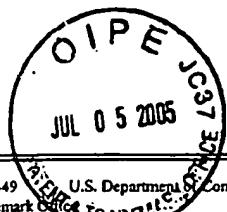


USPTO Form 1449 Patent and Trademark Office U.S. Department of Commerce INFORMATION DISCLOSURE STATEMENT			Attorney Docket No.		Serial No.		
			2846/2112		10/660,348		
			Applicant(s): Ren et al.		Filing Date: September 11, 2003		
					Group: 1775		
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Examiner Initial	Patent No.	Date	Name	Class	Subclas s	Filing Date (if appropriate)	
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Examiner Initial	Document No.	Publication Date	Country	Class	Subclas s	Translation	
						YES	NO
OTHER DOCUMENTS (including Author, Title, Date, Pertinent Pages, etc.)							
A	International Search Report based on PCT/US03/28530 dated April 7, 2005.						
EXAMINER				DATE CONSIDERED			
				10/13/05			
<small>*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.</small>							
<small>**Copies of references not provided at the time of this submission.</small>							



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Examiner Initial		Document No.	Publication Date	Country	Class	Subclas s	Translation	
							YES	NO
OTHER DOCUMENTS (including Author, Title, Date, Pertinent Pages, etc.)								
<i>JKW</i>	A	Park, W.I. et al., <u>Metalorganic Vapor-Phase Epitaxial Growth of Vertically Well-Aligned ZnO Nanorods</u> , Applied Physics Letters, 2002, Vol. 80, No. 22, pp. 4232-4234.						
<i>JKW</i>	B	Park, W.I. et al., <u>ZnO Nanoneedles Grown Vertically on Si Substrates by Non-Catalytic Vapor-Phase Epitaxy</u> , Advanced Materials, 2002, Vol. 14, No. 24, pp. 1841-1843.						
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EXAMINER <i>JKW</i>				DATE CONSIDERED <i>10/13/05</i>				
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